## GaAs Transfer Switch, DC-3.0 GHz

## Features

- Small Ceramic Package, 0.250" Sq.
- Fast Switching Speed, 4 ns Typical
- Ultra Low DC Power Consumption
- 50 Ohm Nominal Impedance
- MIL-STD-883 screening available
- Lead-Free CR-4 Package
- $260^{\circ} \mathrm{C}$ Reflow Compatible


## Description

M/A-COM's SW-283-PIN is a GaAs MMIC transfer switch packaged in lead-free, surface mount CR-4 ceramic style packages. SW-283-PIN offers low insertion loss, high isolation, and fast switching. This ceramic switch platform has a common footprint for all three designs. The CR-4 package is hermetically sealed, making this switch ideal for space, military radios, and other environmentally harsh applications.

Typical applications include synthesizer switching, transmit/receive switching, switch matrices and filter banks in systems such as radio and cellular equipment, PCM, GPS, and fiber optic modules.

The SW-283-PIN transfer switch contains a monolithic GaAs MMIC which is fabricated using a 1.0 micron MESFET process.

## Ordering Information

| Part Number | Package |
| :---: | :---: |
| SW-283-PIN | Bulk Packaging |

Note: Reference Application Note M513 for reel size information.
Note: Die quantity varies.

Functional Block Diagram


## Pin Configuration

| Pin No. | Function | Pin No. | Function |
| :---: | :---: | :---: | :---: |
| 1 | RF1 | 9 | RF3 |
| 2 | GND | 10 | GND |
| 3 | GND | 11 | GND |
| 4 | RF2 | 12 | RF4 |
| 5 | GND | 13 | GND |
| 6 | A | 14 | GND |
| 7 | B | 15 | GND |
| 8 | GND | 16 | GND |

The metal bottom of the case must be connected to RF and DC ground.

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Electrical Specifications： $\mathrm{T}_{\mathrm{A}}=\mathbf{2 5}^{\circ} \mathrm{C}, \mathrm{Z}_{0}=50 \Omega^{1,2}$

| Parameter | Test Conditions | Frequency | Units | Min | Typ | Max |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | － | $\begin{gathered} \mathrm{DC}-3 \mathrm{GHz} \\ \mathrm{DC}-2 \mathrm{GHz} \\ \mathrm{DC}-1 \mathrm{GHz} \\ \mathrm{DC}-0.5 \mathrm{GHz} \end{gathered}$ | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ | $\begin{aligned} & - \\ & - \\ & - \end{aligned}$ | $\begin{aligned} & - \\ & \text { - } \end{aligned}$ | $\begin{aligned} & 2.1 \\ & 1.8 \\ & 1.3 \\ & 1.0 \end{aligned}$ |
| VSWR | － | $\begin{gathered} \mathrm{DC}-3 \mathrm{GHz} \\ \mathrm{DC}-2 \mathrm{GHz} \\ \mathrm{DC}-1 \mathrm{GHz} \\ \mathrm{DC}-0.5 \mathrm{GHz} \end{gathered}$ | Ratio Ratio Ratio Ratio | $\begin{aligned} & - \\ & - \\ & \hline \end{aligned}$ | $\begin{aligned} & \text { 二 } \\ & \text { - } \end{aligned}$ | $\begin{gathered} 1.9: 1 \\ 1.7: 1 \\ 1.3: 1 \\ 1.25: 1 \end{gathered}$ |
| Isolation | － | $\begin{gathered} \mathrm{DC}-3 \mathrm{GHz} \\ \mathrm{DC}-2 \mathrm{GHz} \\ \mathrm{DC}-1 \mathrm{GHz} \\ \mathrm{DC}-0.5 \mathrm{GHz} \end{gathered}$ | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ | $\begin{aligned} & 20 \\ & 25 \\ & 40 \\ & 45 \end{aligned}$ | － | － |
| Trise，Tfall Ton，Toff Transients | 10／90\％or 90／10\％RF 50\％CTL to 90／10\％RF In－Band | - | $\begin{aligned} & \mathrm{nS} \\ & \mathrm{nS} \\ & \mathrm{mV} \end{aligned}$ | 二 | $\begin{gathered} 2 \\ 4 \\ 30 \end{gathered}$ | － |
| 1 dB Compression | Control Voltage 0／－5 VDC <br> Control Voltage 0／－8 VDC | $\begin{gathered} 0.5-3 \mathrm{GHz} \\ 0.05 \mathrm{GHz} \\ 0.5-3 \mathrm{GHz} \\ 0.05 \mathrm{GHz} \end{gathered}$ | dBm dBm dBm dBm | - | $\begin{aligned} & +27 \\ & +21 \\ & +33 \\ & +26 \end{aligned}$ | － |
| $\mathrm{IP}_{2}$ | For two－tone Input power up to +13 dBm | $\begin{gathered} 0.5-3 \mathrm{GHz} \\ 0.05 \mathrm{GHz} \end{gathered}$ | dBm dBm | － | $\begin{aligned} & +68 \\ & +62 \end{aligned}$ | － |
| $\mathrm{IP}_{3}$ | For two－tone Input power up to +13 dBm | $\begin{gathered} 0.5-3 \mathrm{GHz} \\ 0.05 \mathrm{GHz} \end{gathered}$ | dBm dBm | - | $\begin{aligned} & +50 \\ & +45 \end{aligned}$ | － |
| Control Voltages | $\begin{gathered} \mathrm{V}_{\text {IN }} \text { Low: } 0 \text { to }-0.2 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{IN}} \text { High: }-5 \mathrm{~V} @ 10 \mu \mathrm{~A} \text { Typ } \\ \text { to }-8 \mathrm{~V} \end{gathered}$ | 二 | - | - | － | $\begin{gathered} 5 \mu \mathrm{~A} \\ 200 \mu \mathrm{~A} \end{gathered}$ |

1．All specifications apply with 50 ohm impedance connected to all RF ports with 0 and -5 VDC control voltages．
2．Faster switching speed can be achieved with enhanced driver waveform．

## Absolute Maximum Ratings ${ }^{3,4}$

| Parameter | Absolute Maximum |
| :---: | :---: |
| Input Power |  |
| 0.05 GHz | +27 dBm |
| $0.5-3.0 \mathrm{GHz}$ | +34 dBm |
| Control Voltage | $-8.5 \mathrm{~V} \leq \mathrm{Vc} \leq+5 \mathrm{~V}$ |
| Operating Temperature | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

3．Exceeding any one or combination of these limits may cause permanent damage to this device．
4．$M / A-C O M$ does not recommend sustained operation near these survivability limits．

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## Handling Procedures

Please observe the following precautions to avoid damage:

## Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

## Typical Performance Curves

## Insertion Loss vs. Frequency



VSWR vs. Frequency


## Truth Table (Switch)

| Control Input |  | Condition of Switch |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| A | B | RF1- <br> RF2 | RF2- <br> RF3 | RF1- <br> RF4 | RF3- <br> RF4 |
| HI | LOW | OFF | ON | ON | OFF |
| LOW | HI | ON | OFF | OFF | ON |

Low $=0.0 \mathrm{~V}$, High $=-5.0 \mathrm{~V}$

Isolation vs. Frequency


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## Lead-Free, CR-4 Ceramic Package ${ }^{\dagger}$



[^1]
[^0]:    * Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

[^1]:    † Reference Application Note M538 for lead-free solder reflow recommendations.

